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Diodes Incorporated DMC2700UDM-7

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Datasheet of DMC2700UDM-7 - MOSFET N/P-CH 20V SOT26

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DMC2700UDM

20V COMPLEMENTARY PAIR ENHANCEMENT MODE MOSFET

Product Summary

Device	V _{(BR)DSS}	R _{DS(on)} max	I _D max T _A = 25°C (Notes 4)
01	Q1 20V	0.4Ω @ V _{GS} = 4.5V	1.34 A
Qi		0.5Ω @ V _{GS} = 2.5V	1.65 A
00	Q2 -20V -	0.7Ω @ V _{GS} = -4.5V	-1.14 A
Q2		0.9Ω @ V _{GS} = -2.5V	-0.94 A

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208
- Weight: 0.015 grams (approximate)

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage V_{GS(th)} < 1V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Complementary Pair MOSFET
- Ultra-Small Surface Mount Package
- ESD Protected Gate to 2.5kV HBM
- Lead Free/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

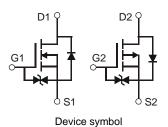
Portable electronics

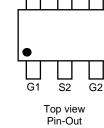




SOT26







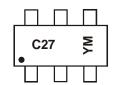
Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMC2700UDM-7	C27	7	8	3,000

Notes: 1. No purposefully added lead.

- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com

Marking Information



C27 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009) M = Month (ex: 9 = September)

Date Code Key

Year	200	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Υ	7	7	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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Maximum Ratings N-CHANNEL − Q₁ @T_A = 25°C unless otherwise specified

Characteris	Symbol	Value	Unit	
Drain Source Voltage		V_{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±6	V
Drain Current (Note 4)	$T_A = 25^{\circ}C$ $T_A = 85^{\circ}C$	I _D	1.34 0.97	А

Maximum Ratings P-CHANNEL − Q₂ @T_A = 25°C unless otherwise specified

Characterist	Symbol	Value	Unit	
Drain Source Voltage	V_{DSS}	-20	V	
Gate-Source Voltage		V_{GSS}	±6	V
Drain Current (Note 4)	$T_A = 25$ °C $T_A = 85$ °C	ln ln	-1.14 -1.07	А

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_{D}	1.12	W
Thermal Resistance, Junction to Ambient (Note 4)	$R_{ hetaJA}$	111	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 4. For a device mounted on 25mm X 25mm FR-4 PCB board with a high coverage of single sided 1oz copper, in still air conditions with two active die

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Electrical Characteristics N-CHANNEL – Q_1 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)				·	·		
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V$, $I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	100	nA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	± 1.0	μΑ	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(th)}	0.5		1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
		_	0.3	0.4		$V_{GS} = 4.5V, I_D = 600mA$	
Static Drain-Source On-Resistance	R _{DS (ON)}	_	0.4	0.5	Ω	$V_{GS} = 2.5V, I_D = 500mA$	
			0.5	0.7		$V_{GS} = 1.8V, I_D = 350mA$	
Forward Transfer Admittance	Y _{fs}		1.4	_	S	$V_{DS} = 10V, I_D = 400mA$	
Diode Forward Voltage (Note 5)	V _{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 150mA$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	I	60.67	_	pF	1/ 401/1/ 01/	
Output Capacitance	Coss	I	9.68	_	pF	$V_{DS} = 16V, V_{GS} = 0V$ - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	I	5.37	_	pF	I = I.OWII IZ	
Total Gate Charge	Qg		736.6	_		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	
Gate-Source Charge	Qgs	_	93.6	_	рC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_{D} = 250 \text{mA}$	
Gate-Drain Charge	Q _{gd}	_	116.6	_		ID = 250IIIA	
Turn-On Delay Time	t _{d(on)}	_	5.1	_		101/11/151/	
Turn-On Rise Time	t _r	_	7.4	_		$V_{DD} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t _{d(off)}	_	26.7	_	ns	$R_L = 47\Omega$, $R_G = 10\Omega$,	
Turn-Off Fall Time	t _f		12.3	_		$I_D = 200 \text{mA}$	

Electrical Characteristics P-CHANNEL - Q₂ @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)			71				
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	± 1.0	μΑ	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(th)}	-0.5	_	-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
		_	0.5	0.7		$V_{GS} = -4.5V$, $I_D = -430mA$	
Static Drain-Source On-Resistance	R _{DS (ON)}		0.7	0.9	Ω	$V_{GS} = -2.5V, I_D = -300mA$	
			1.0	1.3		$V_{GS} = -1.8V, I_D = -150mA$	
Forward Transfer Admittance	Y _{fs}	_	-0.9	_	S	$V_{DS} = 10V, I_D = -250mA$	
Diode Forward Voltage (Note 5)	V_{SD}	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -150mA$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	_	59.76	_	pF	101/11/101/	
Output Capacitance	Coss	_	12.07	_	pF	$V_{DS} = -16V, V_{GS} = 0V$ - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	6.36	_	pF	1 = 1.0IVII IZ	
Total Gate Charge	Qg	_	622.4	_		V 45V V 40V	
Gate-Source Charge	Q _{gs}	_	100.3	_	рC	$V_{GS} = -4.5V, V_{DS} = -10V,$ $I_{D} = -250\text{mA}$	
Gate-Drain Charge	Q_{gd}	_	132.2	_		ID = -250MA	
Turn-On Delay Time	t _{d(on)}	_	5.1	_		101/1/	
Turn-On Rise Time	t _r	_	8.1	_	no	$V_{DD} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t _{d(off)}	_	28.4	_	ns	$R_L = 47\Omega$, $R_G = 10\Omega$,	
Turn-Off Fall Time	t _f	_	20.7	_		$I_D = -200 \text{mA}$	

Notes: 5. Short duration pulse test used to minimize self-heating effect.

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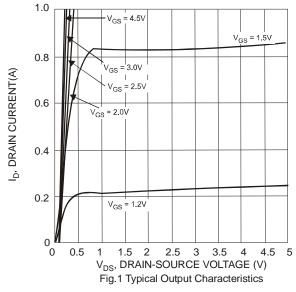
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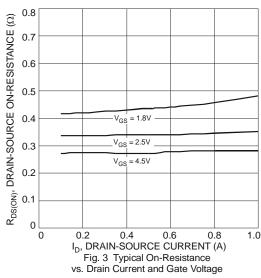


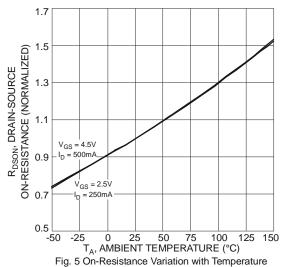
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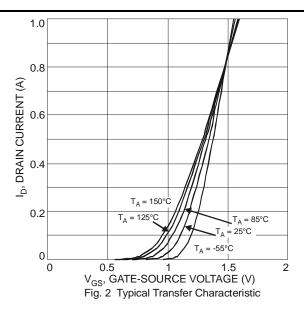
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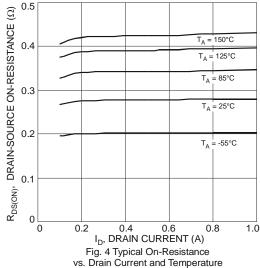
N-CHANNEL - Q₁

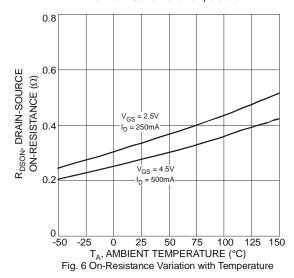












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N-CHANNEL - Q1 (continued)

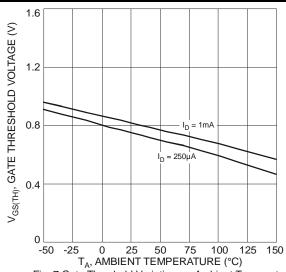
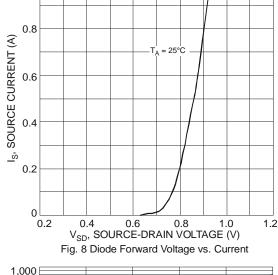
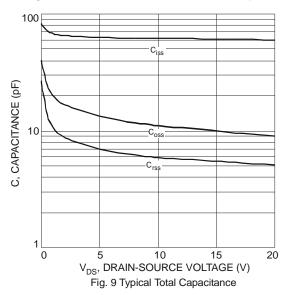


Fig. 7 Gate Threshold Variation vs. Ambient Temperature





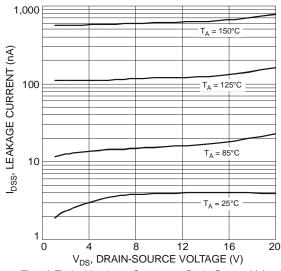


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

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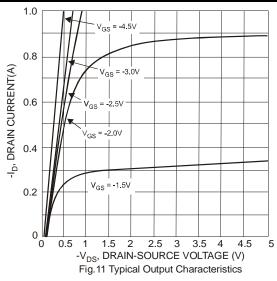
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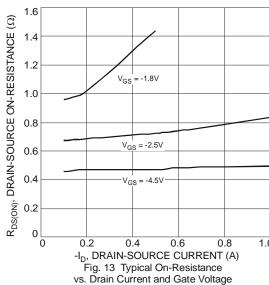


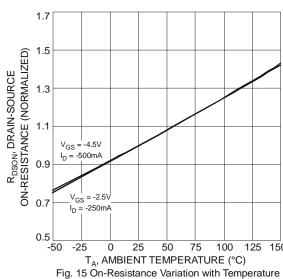
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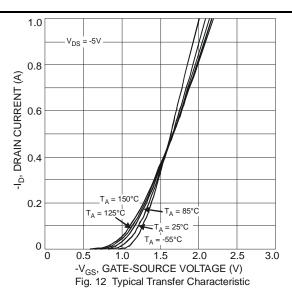
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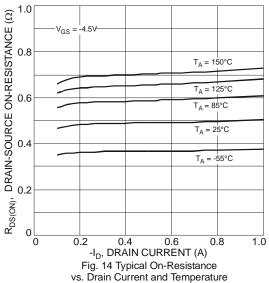
P-CHANNEL - Q₂

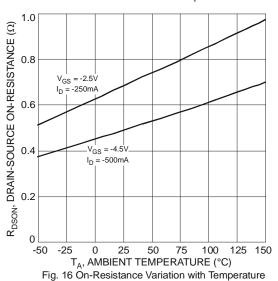












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P-CHANNEL - Q₂ (continued)

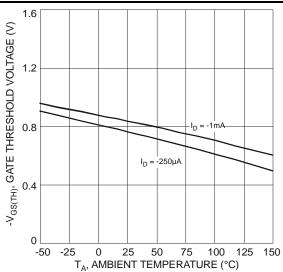
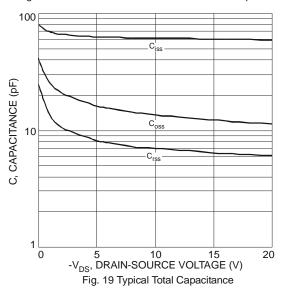
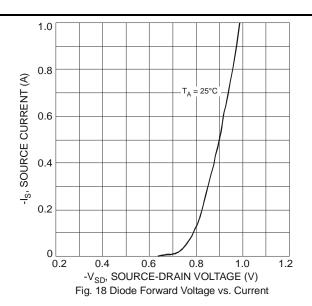
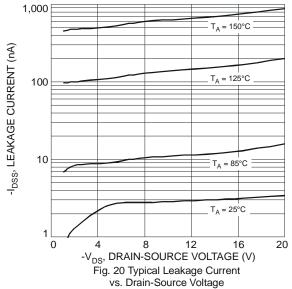


Fig. 17 Gate Threshold Variation vs. Ambient Temperature







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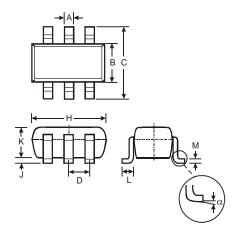
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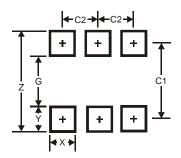
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Package Outline Dimensions



	SOT26					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
C	2.70	3.00	2.80			
D		_	0.95			
Н	2.90	3.10	3.00			
7	0.013	0.10	0.05			
K	1.00	1.30	1.10			
ا ـ	0.35	0.55	0.40			
M	0.10	0.20	0.15			
d	0°	8°				
All D	All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95



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